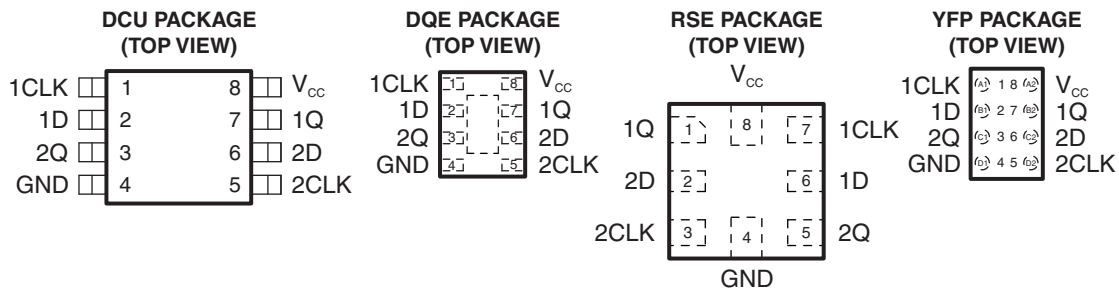


## LOW-POWER DUAL POSITIVE EDGE-TRIGGERED D-TYPE FLIP-FLOP

Check for Samples: [SN74AUP2G79](#)

### FEATURES

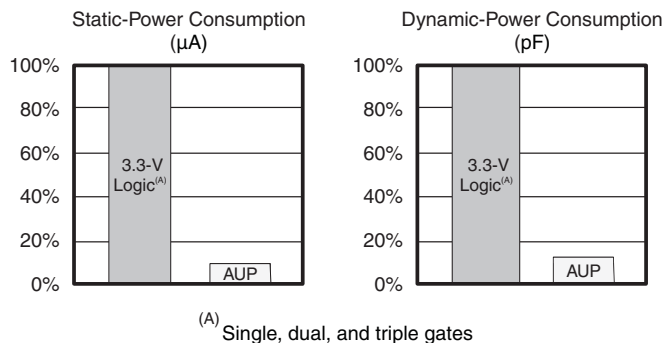
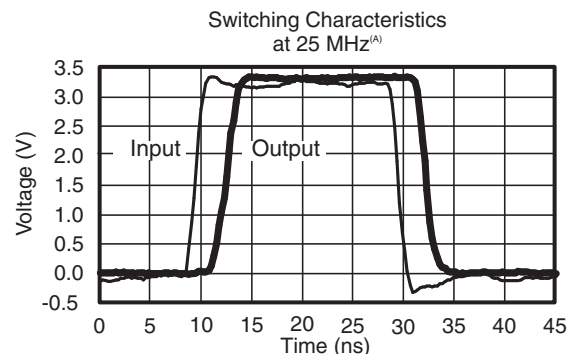
- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption ( $I_{CC} = 0.9 \mu\text{A}$  Maximum)
- Low Dynamic-Power Consumption ( $C_{pd} = 3 \text{ pF}$  Typ at 3.3 V)
- Low Input Capacitance ( $C_i = 1.5 \text{ pF}$  Typical)
- Low Noise – Overshoot and Undershoot <math><10\%</math> of  $V_{CC}$
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Wide Operating  $V_{CC}$  Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- $t_{pd} = 4 \text{ ns}$  Maximum at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

### DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire  $V_{CC}$  range of 0.8 V to 3.6 V, resulting in increased battery life (see [Figure 1](#)). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in [Figure 2](#)).


**Figure 1. AUP – The Lowest-Power Family**

<sup>(A)</sup> SN74AUP2Gxx data at  $C_L = 15 \text{ pF}$ .

**Figure 2. Excellent Signal Integrity**


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar is a trademark of Texas Instruments.

When data at the data (D) input meets the setup time requirement, the data is transferred to the Q output on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

NanoStar™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

**ORDERING INFORMATION<sup>(1)</sup>**

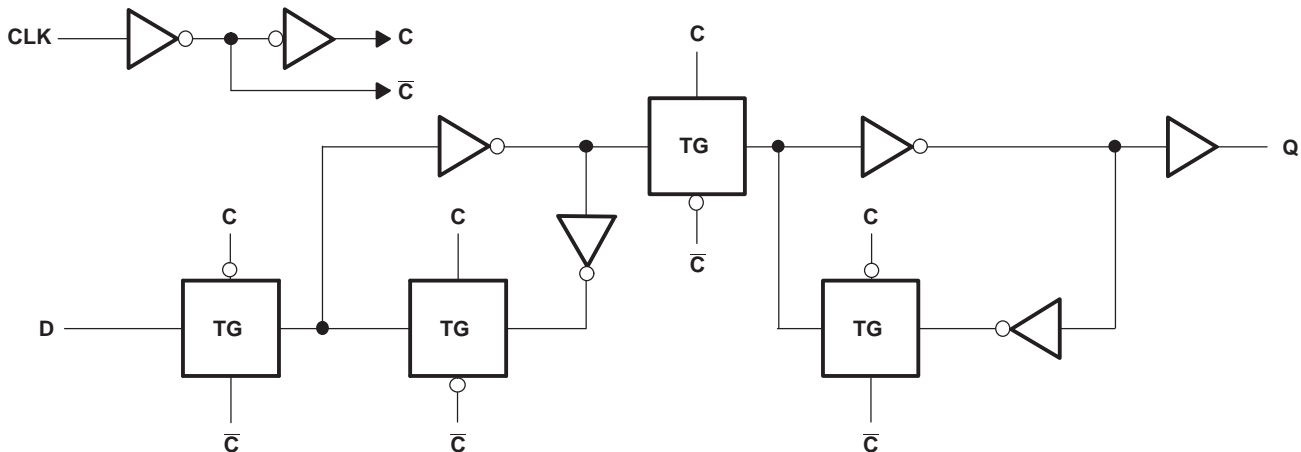
T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(3)</sup>
-40°C to 85°C	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP2G79YFPR	_ _ H W _
	uQFN – DQE	Reel of 5000	SN74AUP2G79DQER	PT
	QFN – RSE	Reel of 5000	SN74AUP2G79RSEER	PT
	SSOP – DCU	Reel of 3000	SN74AUP2G79DCUR	H79_

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).
- (2) Package drawings, thermal data, and symbolization are available at [www.ti.com/packaging](http://www.ti.com/packaging).
- (3) DCU: The actual top-side marking has one additional character that designates the wafer fab/assembly site.  
YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

**FUNCTION TABLE**

INPUTS		OUTPUT
CLK	D	Q
↑	H	H
↑	L	L
L	X	Q <sub>0</sub>
H	X	Q <sub>0</sub>

**LOGIC DIAGRAM, EACH FLIP-FLOP (POSITIVE LOGIC)**



Pin numbers shown are for the DCU and DQE packages.

**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

over operating free-air temperature range (unless otherwise noted)

			<b>MIN</b>	<b>MAX</b>	<b>UNIT</b>
$V_{CC}$	Supply voltage range		-0.5	4.6	V
$V_I$	Input voltage range <sup>(2)</sup>		-0.5	4.6	V
$V_O$	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>		-0.5	4.6	V
$V_O$	Output voltage range in the high or low state <sup>(2)</sup>		-0.5	$V_{CC} + 0.5$	V
$I_{IK}$	Input clamp current	$V_I < 0$		-50	mA
$I_{OK}$	Output clamp current	$V_O < 0$		-50	mA
$I_O$	Continuous output current			±20	mA
	Continuous current through $V_{CC}$ or GND			±50	mA
$\theta_{JA}$	Package thermal impedance <sup>(3)</sup>	DCU package		220	°C/W
		DQE package		261	
		RSE package		253	
		YFP package		132	
$T_{stg}$	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The package thermal impedance is calculated in accordance with JEDEC 51-7.

**RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>**

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	0.8	3.6	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.65 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	
		V <sub>CC</sub> = 3 V to 3.6 V	2	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 0.8 V	0	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.35 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7	
		V <sub>CC</sub> = 3 V to 3.6 V	0.9	
V <sub>I</sub>	Input voltage	0	3.6	V
V <sub>O</sub>	Output voltage	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 0.8 V	–20	mA
		V <sub>CC</sub> = 1.1 V	–1.1	
		V <sub>CC</sub> = 1.4 V	–1.7	
		V <sub>CC</sub> = 1.65 V	–1.9	
		V <sub>CC</sub> = 2.3 V	–3.1	
		V <sub>CC</sub> = 3 V	–4	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 0.8 V	20	mA
		V <sub>CC</sub> = 1.1 V	1.1	
		V <sub>CC</sub> = 1.4 V	1.7	
		V <sub>CC</sub> = 1.65 V	1.9	
		V <sub>CC</sub> = 2.3 V	3.1	
		V <sub>CC</sub> = 3 V	4	
Δt/Δv	Input transition rise or fall rate		200	ns/V
T <sub>A</sub>	Operating free-air temperature	–40	85	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = –40°C to 85°C		UNIT
			MIN	TYP	MAX	MIN	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = –20 μA	0.8 V to 3.6 V	V <sub>CC</sub> – 0.1			V <sub>CC</sub> – 0.1		V
	I <sub>OH</sub> = –1.1 mA	1.1 V	0.75 × V <sub>CC</sub>			0.7 × V <sub>CC</sub>		
	I <sub>OH</sub> = –1.7 mA	1.4 V	1.11			1.03		
	I <sub>OH</sub> = –1.9 mA	1.65 V	1.32			1.3		
	I <sub>OH</sub> = –2.3 mA	2.3 V	2.05			1.97		
	I <sub>OH</sub> = –3.1 mA		1.9			1.85		
	I <sub>OH</sub> = –2.7 mA	3 V	2.72			2.67		
	I <sub>OH</sub> = –4 mA		2.6			2.55		
V <sub>OL</sub>	I <sub>OL</sub> = 20 μA	0.8 V to 3.6 V	0.1			0.1		V
	I <sub>OL</sub> = 1.1 mA	1.1 V	0.3 × V <sub>CC</sub>			0.3 × V <sub>CC</sub>		
	I <sub>OL</sub> = 1.7 mA	1.4 V	0.31			0.37		
	I <sub>OL</sub> = 1.9 mA	1.65 V	0.31			0.35		
	I <sub>OL</sub> = 2.3 mA	2.3 V	0.31			0.33		
	I <sub>OL</sub> = 3.1 mA		0.44			0.45		
	I <sub>OL</sub> = 2.7 mA	3 V	0.31			0.33		
	I <sub>OL</sub> = 4 mA		0.44			0.45		
I <sub>I</sub>	A or B input	V <sub>I</sub> = GND to 3.6 V	0 V to 3.6 V			0.1	0.5	μA
I <sub>off</sub>		V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V	0 V			0.2	0.6	μA
ΔI <sub>off</sub>		V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V	0 V to 0.2 V			0.2	0.6	μA
I <sub>CC</sub>		V <sub>I</sub> = GND or (V <sub>CC</sub> to 3.6 V), I <sub>O</sub> = 0	0.8 V to 3.6 V			0.5	0.9	μA
ΔI <sub>CC</sub>		V <sub>I</sub> = V <sub>CC</sub> – 0.6 V <sup>(1)</sup> , I <sub>O</sub> = 0	3.3 V			40	50	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	0 V	1.5					pF
		3.6 V	1.5					
C <sub>o</sub>	V <sub>O</sub> = GND	0 V	3					pF

 (1) One input at V<sub>CC</sub> – 0.6 V, other input at V<sub>CC</sub> or GND

**TIMING REQUIREMENTS**

over recommended operating free-air temperature range (unless otherwise noted) (see [Figure 4](#))

		V <sub>CC</sub>	T <sub>A</sub> = 25°C	T <sub>A</sub> = -40°C to 85°C	UNIT
			TYP	MIN MAX	
f <sub>clock</sub>	Clock frequency	0.8 V		20	MHz
		1.2 V ± 0.1 V		80	
		1.5 V ± 0.1 V		100	
		1.8 V ± 0.15 V		140	
		2.5 V ± 0.2 V		210	
		3.3 V ± 0.3 V		260	
t <sub>w</sub>	Pulse duration, CLK high or low	0.8 V		4.8	ns
		1.2 V ± 0.1 V		2.2	
		1.5 V ± 0.1 V		1.5	
		1.8 V ± 0.15 V		1.6	
		2.5 V ± 0.2 V		1.7	
		3.3 V ± 0.3 V		1.9	
t <sub>su</sub>	Data high	0.8 V	2.9	4.2	ns
		1.2 V ± 0.1 V		1.4	
		1.5 V ± 0.1 V		1	
		1.8 V ± 0.15 V		0.9	
		2.5 V ± 0.2 V		0.7	
		3.3 V ± 0.3 V		0.6	
	Data low	0.8 V	3.5	5.3	
		1.2 V ± 0.1 V		1.8	
		1.5 V ± 0.1 V		1.2	
		1.8 V ± 0.15 V		1.1	
		2.5 V ± 0.2 V		1	
		3.3 V ± 0.3 V		1	
t <sub>h</sub>	Hold time, data after CLK↑	0.8 V	0	0	ns
		1.2 V ± 0.1 V		0	
		1.5 V ± 0.1 V		0	
		1.8 V ± 0.15 V		0	
		2.5 V ± 0.2 V		0	
		3.3 V ± 0.3 V		0	

## SWITCHING CHARACTERISTICS

 over recommended operating free-air temperature range,  $C_L = 5$  pF (unless otherwise noted) (see [Figure 3](#) and [Figure 4](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$		UNIT
				MIN	TYP	MAX	MIN	MAX	
$f_{\max}$			0.8 V		93		90		MHz
			$1.2\text{ V} \pm 0.1\text{ V}$		199		220		
			$1.5\text{ V} \pm 0.1\text{ V}$		250		230		
			$1.8\text{ V} \pm 0.15\text{ V}$		271		240		
			$2.5\text{ V} \pm 0.2\text{ V}$		280		250		
			$3.3\text{ V} \pm 0.3\text{ V}$		280		260		
$t_{pd}$	CLK	Q	0.8 V		15.9				ns
			$1.2\text{ V} \pm 0.1\text{ V}$	3.7	6.9	11	2.6	13.1	
			$1.5\text{ V} \pm 0.1\text{ V}$	3	4.8	7.6	2	8.8	
			$1.8\text{ V} \pm 0.15\text{ V}$	2.4	3.8	6.1	1.5	7.1	
			$2.5\text{ V} \pm 0.2\text{ V}$	1.8	2.7	4.4	1.1	5	
			$3.3\text{ V} \pm 0.3\text{ V}$	1.5	2.1	3.6	0.9	4	

## SWITCHING CHARACTERISTICS

 over recommended operating free-air temperature range,  $C_L = 10$  pF (unless otherwise noted) (see [Figure 3](#) and [Figure 4](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$		UNIT
				MIN	TYP	MAX	MIN	MAX	
$f_{\max}$			0.8 V		62		50		MHz
			$1.2\text{ V} \pm 0.1\text{ V}$		147		160		
			$1.5\text{ V} \pm 0.1\text{ V}$		189		200		
			$1.8\text{ V} \pm 0.15\text{ V}$		180		240		
			$2.5\text{ V} \pm 0.2\text{ V}$		260		250		
			$3.3\text{ V} \pm 0.3\text{ V}$		280		260		
$t_{pd}$	CLK	Q	0.8 V		18				ns
			$1.2\text{ V} \pm 0.1\text{ V}$	4.3	7.8	12.3	3.2	14.4	
			$1.5\text{ V} \pm 0.1\text{ V}$	3.5	5.5	8.4	2.5	9.8	
			$1.8\text{ V} \pm 0.15\text{ V}$	2.8	4.4	6.8	1.9	8	
			$2.5\text{ V} \pm 0.2\text{ V}$	2.2	3.2	5	1.5	5.7	
			$3.3\text{ V} \pm 0.3\text{ V}$	1.8	2.6	4.1	1.3	4.5	

## SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 15$  pF (unless otherwise noted) (see [Figure 3](#) and [Figure 4](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$		UNIT
				MIN	TYP	MAX	MIN	MAX	
$f_{\max}$			0.8 V	48			30		MHz
			$1.2\text{ V} \pm 0.1\text{ V}$	112			120		
			$1.5\text{ V} \pm 0.1\text{ V}$	151			160		
			$1.8\text{ V} \pm 0.15\text{ V}$	194			220		
			$2.5\text{ V} \pm 0.2\text{ V}$	248			250		
			$3.3\text{ V} \pm 0.3\text{ V}$	280			260		
$t_{pd}$	CLK	Q	0.8 V	20.3					ns
			$1.2\text{ V} \pm 0.1\text{ V}$	5	8.7	13.6	3.9	15.6	
			$1.5\text{ V} \pm 0.1\text{ V}$	4.1	6.3	9.3	3.1	10.7	
			$1.8\text{ V} \pm 0.15\text{ V}$	3.3	4	7.6	2.4	8.7	
			$2.5\text{ V} \pm 0.2\text{ V}$	2.6	3.6	5.5	1.9	6.3	
			$3.3\text{ V} \pm 0.3\text{ V}$	2.2	3	4.5	1.6	5	

## SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 30$  pF (unless otherwise noted) (see [Figure 3](#) and [Figure 4](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$		UNIT
				MIN	TYP	MAX	MIN	MAX	
$f_{\max}$			0.8 V	24			20		MHz
			$1.2\text{ V} \pm 0.1\text{ V}$	72			80		
			$1.5\text{ V} \pm 0.1\text{ V}$	100			100		
			$1.8\text{ V} \pm 0.15\text{ V}$	127			140		
			$2.5\text{ V} \pm 0.2\text{ V}$	185			210		
			$3.3\text{ V} \pm 0.3\text{ V}$	266			260		
$t_{pd}$	CLK	Q	0.8 V	27.2					ns
			$1.2\text{ V} \pm 0.1\text{ V}$	7	11.5	17.3	5.9	24	
			$1.5\text{ V} \pm 0.1\text{ V}$	5.7	8.3	13.3	4.6	15.9	
			$1.8\text{ V} \pm 0.15\text{ V}$	4.7	6.7	11.3	3.8	13	
			$2.5\text{ V} \pm 0.2\text{ V}$	3.7	4.9	7.8	2.9	9	
			$3.3\text{ V} \pm 0.3\text{ V}$	3.2	4.1	6.3	2.6	7.2	

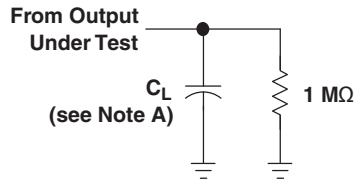
## OPERATING CHARACTERISTICS

$T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	$V_{CC}$	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	$f = 10\text{ MHz}$	0.8 V	2.5	pF
			$1.2\text{ V} \pm 0.1\text{ V}$	2.5	
			$1.5\text{ V} \pm 0.1\text{ V}$	2.5	
			$1.8\text{ V} \pm 0.15\text{ V}$	2.5	
			$2.5\text{ V} \pm 0.2\text{ V}$	3	
			$3.3\text{ V} \pm 0.3\text{ V}$	3	

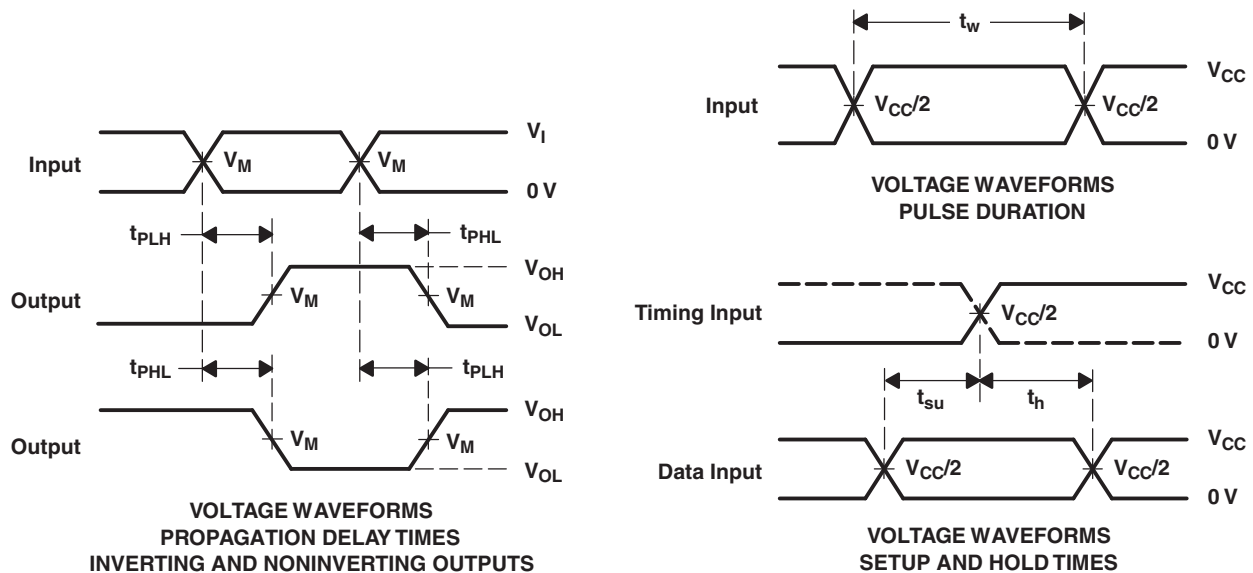


**PARAMETER MEASUREMENT INFORMATION**  
(Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

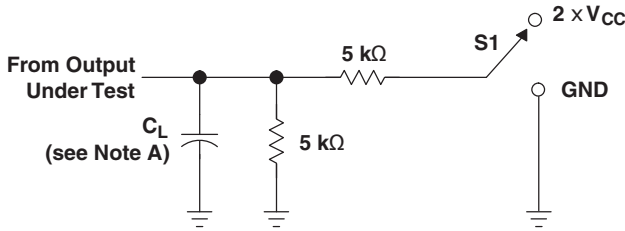
	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V}$ $\pm 0.1\text{ V}$	$V_{CC} = 1.5\text{ V}$ $\pm 0.1\text{ V}$	$V_{CC} = 1.8\text{ V}$ $\pm 0.15\text{ V}$	$V_{CC} = 2.5\text{ V}$ $\pm 0.2\text{ V}$	$V_{CC} = 3.3\text{ V}$ $\pm 0.3\text{ V}$
$C_L$	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
$V_M$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
$V_I$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$



- A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ , for propagation delays  $t_r/t_f = 3\text{ ns}$ , for setup and hold times and pulse width  $t_r/t_f = 1.2\text{ ns}$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- F. All parameters and waveforms are not applicable to all devices.

**Figure 3. Load Circuit and Voltage Waveforms**

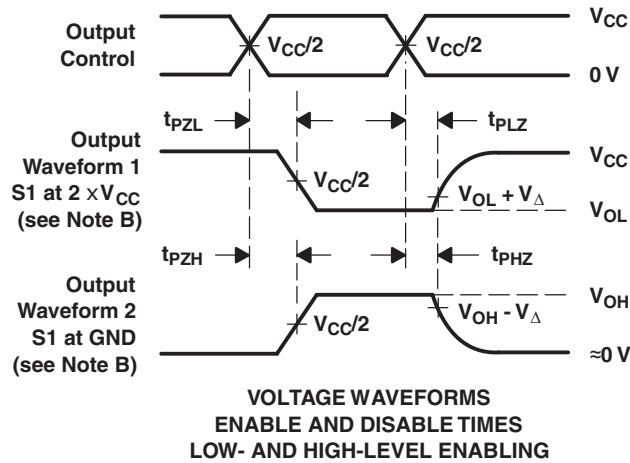
**PARAMETER MEASUREMENT INFORMATION  
(Enable and Disable Times)**



TEST	S1
$t_{PLZ}/t_{PZL}$	$2 \times V_{CC}$
$t_{PHZ}/t_{PZH}$	GND

**LOAD CIRCUIT**

	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V} \pm 0.1\text{ V}$	$V_{CC} = 1.5\text{ V} \pm 0.1\text{ V}$	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$	$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$	$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$
$C_L$	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
$V_M$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
$V_I$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$
$V_{\Delta}$	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



**VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING**

- A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r/t_f = 3\text{ ns}$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- G. All parameters and waveforms are not applicable to all devices.

**Figure 4. Load Circuit and Voltage Waveforms**

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**REVISION HISTORY**

<b>Changes from Revision B (March 2010) to Revision C</b>	<b>Page</b>
• Added clock high to FUNCTION TABLE. ....	<a href="#">2</a>

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**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AUP2G79DCUR	ACTIVE	VSSOP	DCU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H79R	<a href="#">Samples</a>
SN74AUP2G79DQER	ACTIVE	X2SON	DQE	8	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	PT	<a href="#">Samples</a>
SN74AUP2G79RSER	ACTIVE	UQFN	RSE	8	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	PT	<a href="#">Samples</a>
SN74AUP2G79YFPR	ACTIVE	DSBGA	YFP	8	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	HWN	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

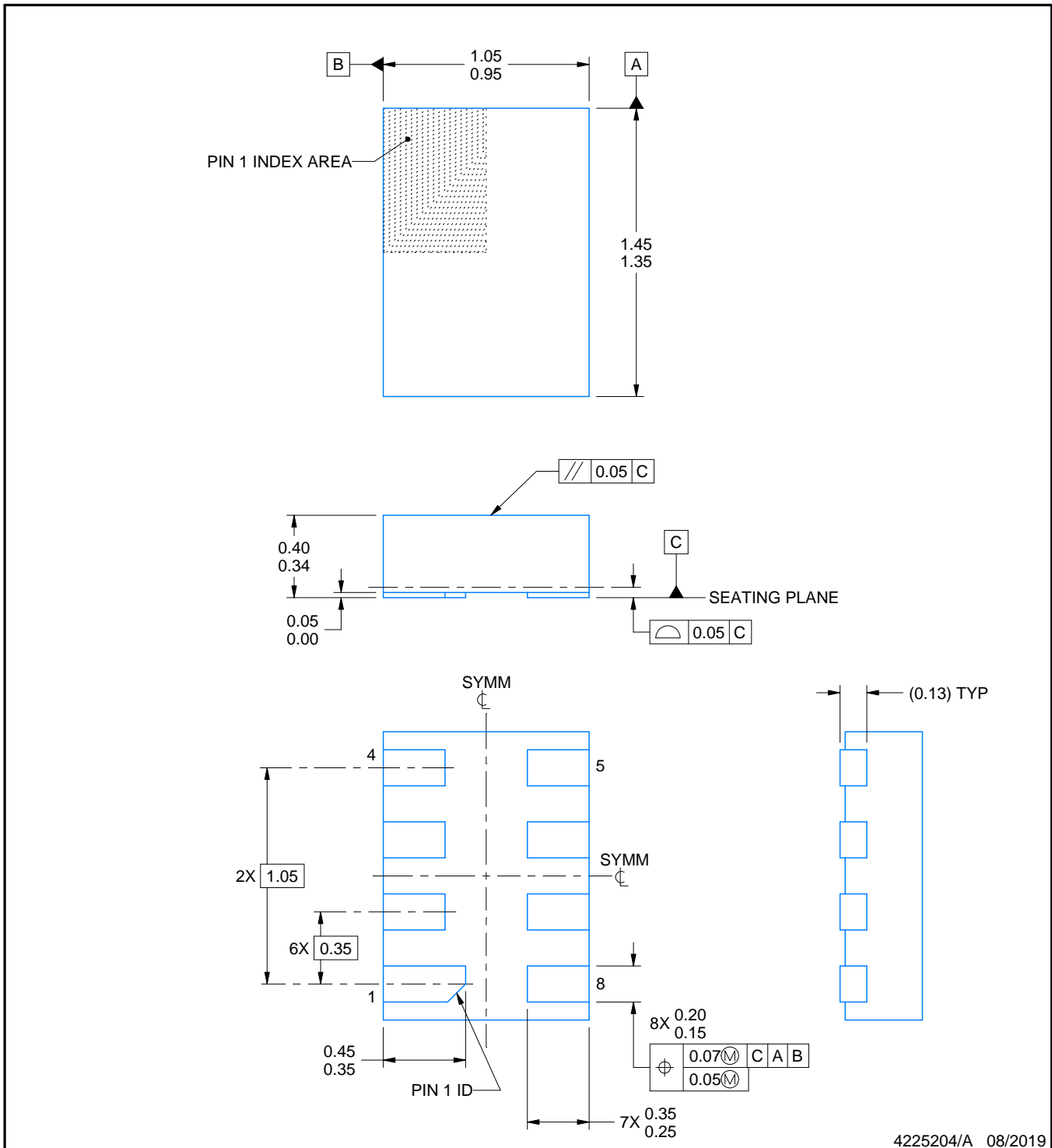

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP2G79DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AUP2G79DQER	X2SON	DQE	8	5000	180.0	8.4	1.2	1.6	0.55	4.0	8.0	Q1
SN74AUP2G79RSER	UQFN	RSE	8	5000	180.0	8.4	1.7	1.7	0.7	4.0	8.0	Q2
SN74AUP2G79YFPR	DSBGA	YFP	8	3000	178.0	9.2	0.9	1.75	0.6	4.0	8.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP2G79DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74AUP2G79DQER	X2SON	DQE	8	5000	202.0	201.0	28.0
SN74AUP2G79RSER	UQFN	RSE	8	5000	202.0	201.0	28.0
SN74AUP2G79YFPR	DSBGA	YFP	8	3000	220.0	220.0	35.0



4225204/A 08/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package complies to JEDEC MO-287 variation X2EAF.



# EXAMPLE BOARD LAYOUT

DQE0008A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 40X



SOLDER MASK DETAILS

4225204/A 08/2019

NOTES: (continued)

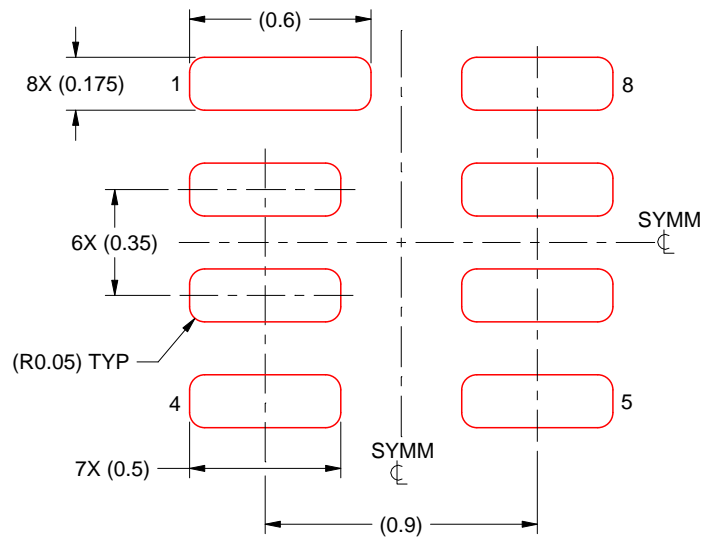
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).

# EXAMPLE STENCIL DESIGN

DQE0008A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.075 MM THICK STENCIL  
SCALE: 40X

4225204/A 08/2019

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

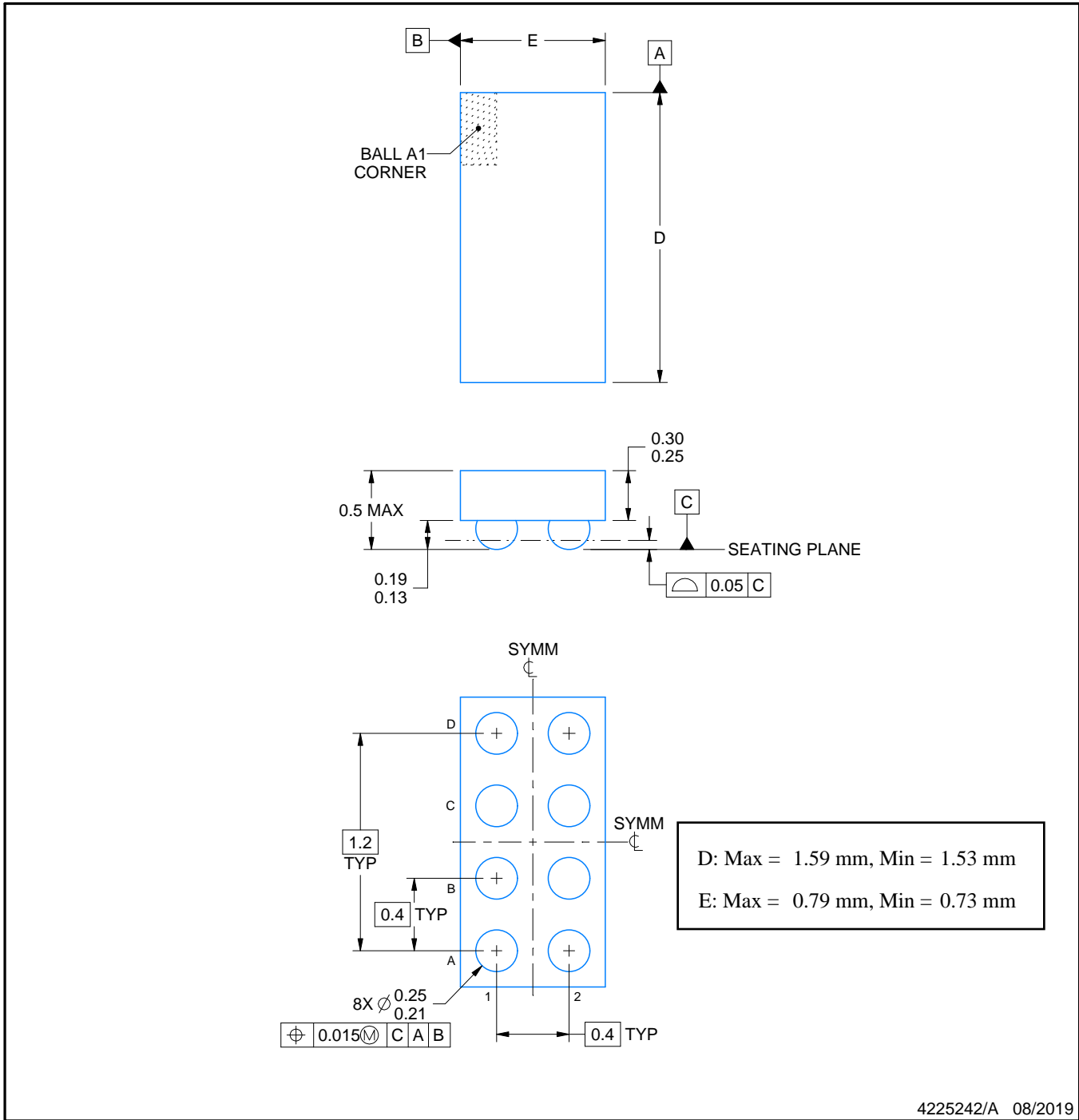
YFP0008



# PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

YFP0008

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 50X



SOLDER MASK DETAILS  
NOT TO SCALE

4225242/A 08/2019

NOTES: (continued)

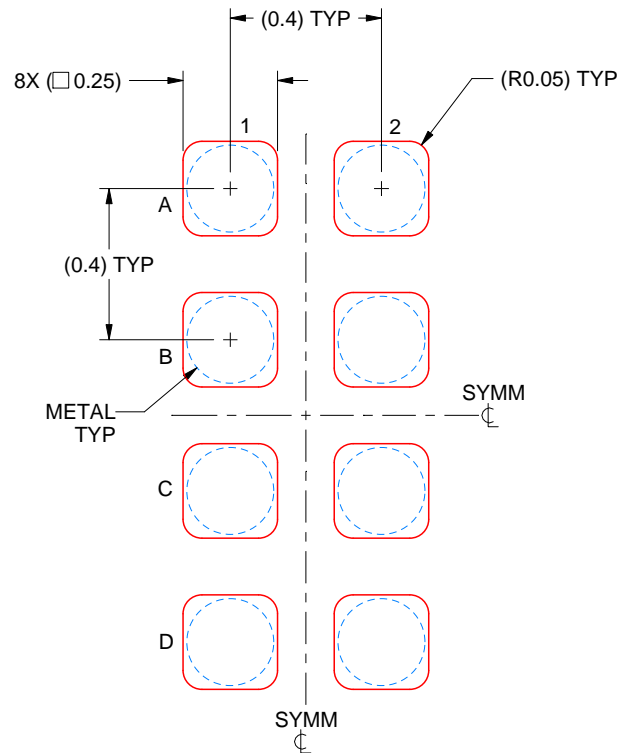
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

# EXAMPLE STENCIL DESIGN

YFP0008

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY

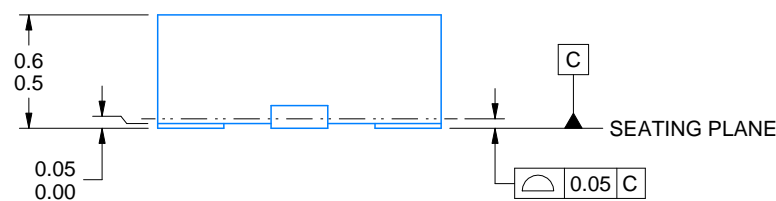
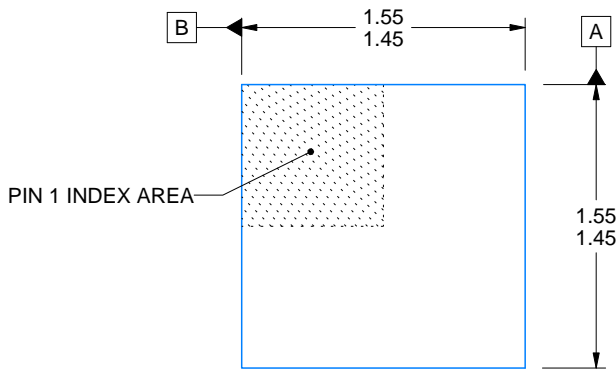


SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE: 50X

4225242/A 08/2019

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



4220323/B 03/2018

NOTES:

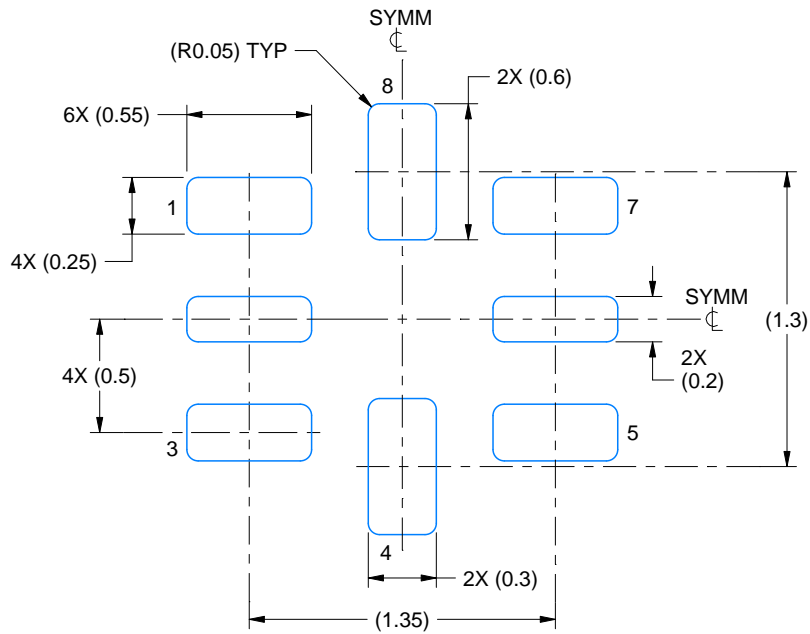
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

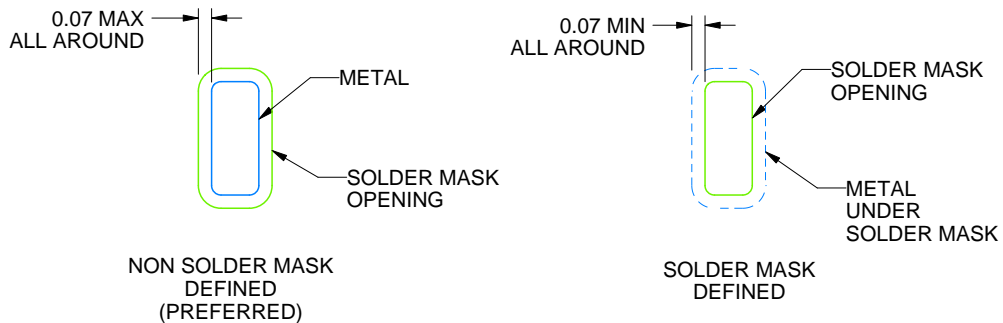
RSE0008A

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:30X



SOLDER MASK DETAILS  
NOT TO SCALE

4220323/B 03/2018

NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).

# EXAMPLE STENCIL DESIGN

RSE0008A

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICKNESS  
SCALE: 30X

4220323/B 03/2018

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





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